

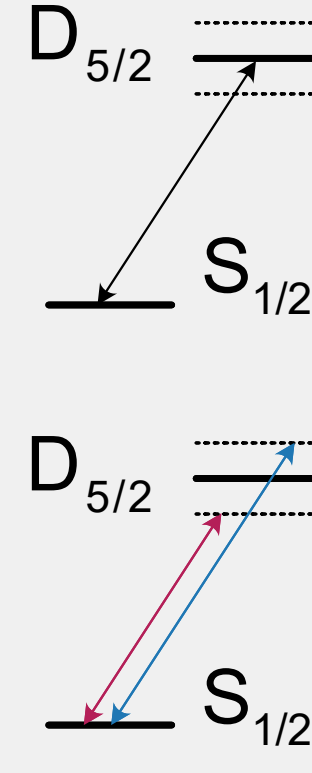
Next generation platform for implementing fast gates in ion trap quantum computation

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Scalable trapped-ion quantum computation relies on the development of high-fidelity fast entangling gates in a many ion crystal. Conventional geometric phase gates either suffer from scattering errors or off-resonant carrier excitations. A potential route to achieve fast entanglement is creating a standing wave which can suppress the unwanted carrier coupling.

Non-Adiabatic Mølmer Sørensen Gates

- Two qubit gates are implemented by coupling spin with shared motion of the ions.
- Fast entangling gates enable deeper quantum computational circuits for a given level of incoherent error.
- Mølmer Sørensen (MS) interaction is common two-qubit gate which requires a bichromatic field incident on the ions. Using a quadrupole transition, travelling wave to interact with the ions gives the Hamiltonian



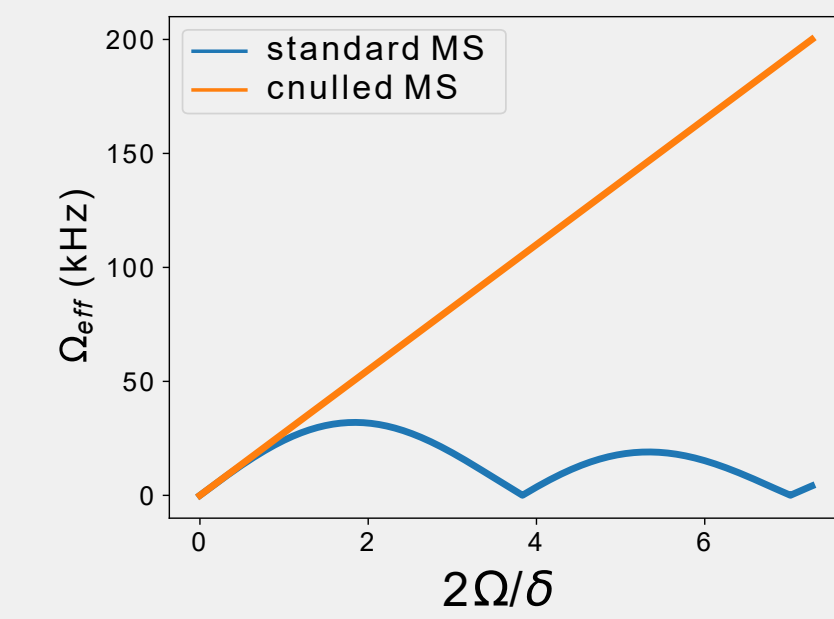
$$\hat{H}_{MS-TW} = \hbar\Omega\hat{S}_{\phi-\pi/2}\cos(\delta t) + \hbar\Omega\eta\hat{S}_{\phi}\cos(\delta t)(\hat{a}e^{-i\omega_z t} + \hat{a}^{\dagger}e^{i\omega_z t})$$

with the first term being the carrier whilst the second is the desired coupling.

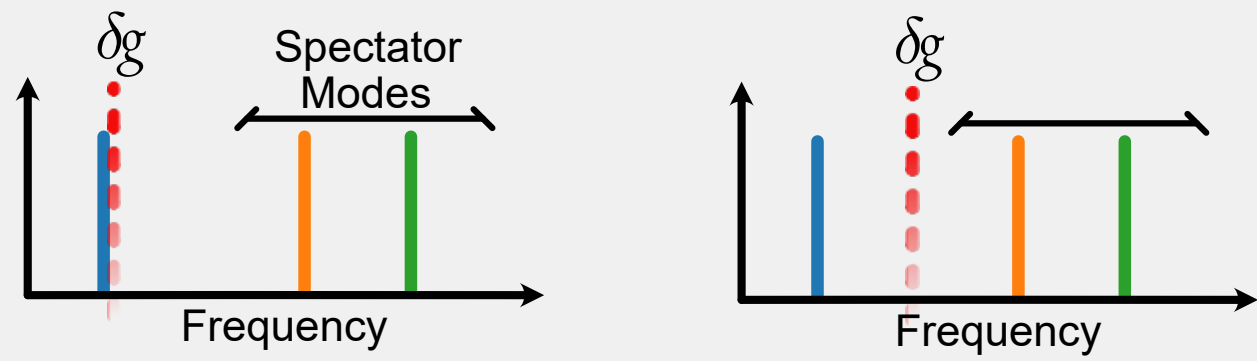
- As these terms do not commute, in the interaction picture this Hamiltonian may be expressed as [1]:

$$\hat{H}_{MS-TW} = \hbar\eta\Omega(J_0(2\Omega/\delta) + J_2(2\Omega/\delta)) \cdot \cos(\delta t)\hat{S}_{\phi}(\hat{a}e^{-i\omega_z t} + \hat{a}^{\dagger}e^{i\omega_z t})$$

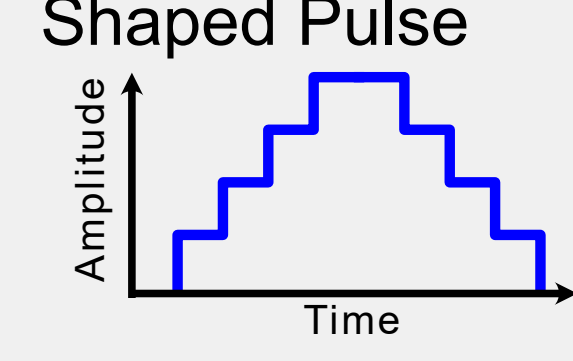
- Carrier term:** causes the spin dependent force coupling to be modulated by (J_0+J_2) .
- Non-Adiabatic (fast) gates excite multiple motional modes ("spectator modes") which can introduce errors.
- Spectator excitation:** Amplitude shaped pulses [2] effectively remove "spectator" error by closing phase loops of all excited modes.



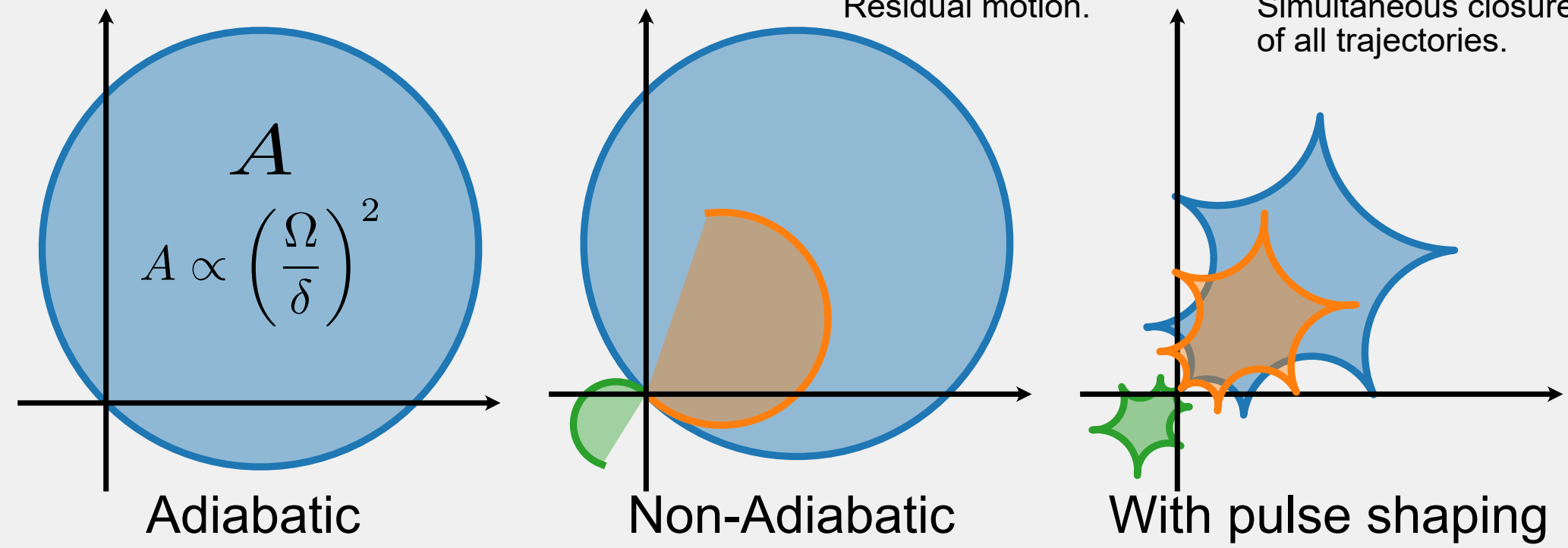
Motional Frequencies



Amplitude Shaped Pulse



Motional Phase Space

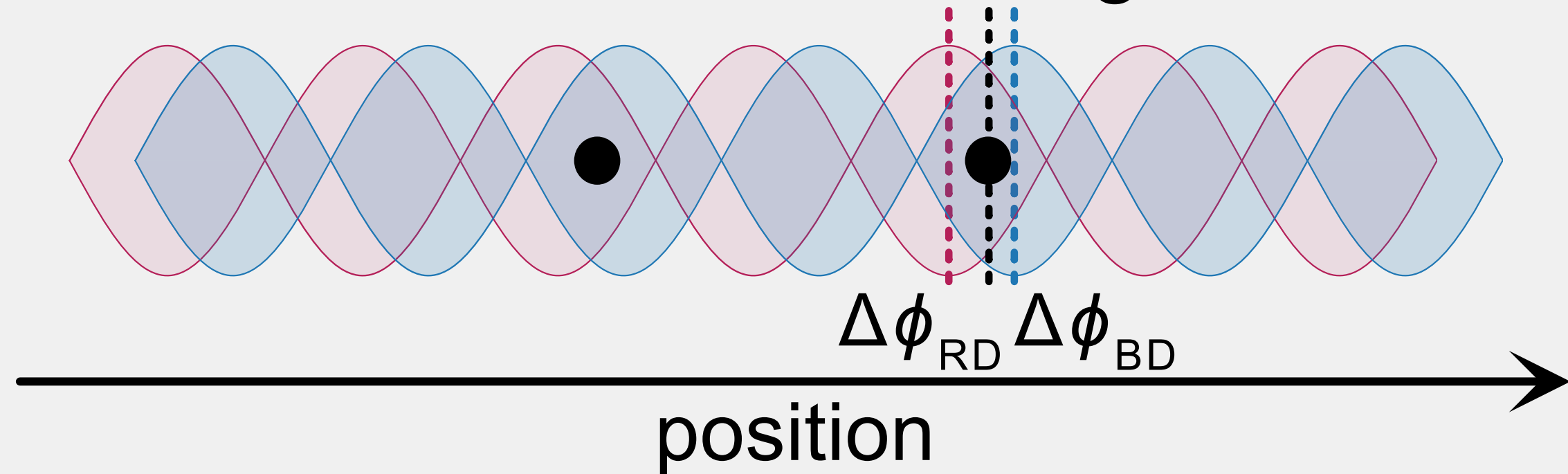


Standing Wave Single and MS Gates

- Using standing wave gives complete control over phase visible to ions.
- Bichromatic standing wave Hamiltonian where ions are separated by $n\lambda/2$:

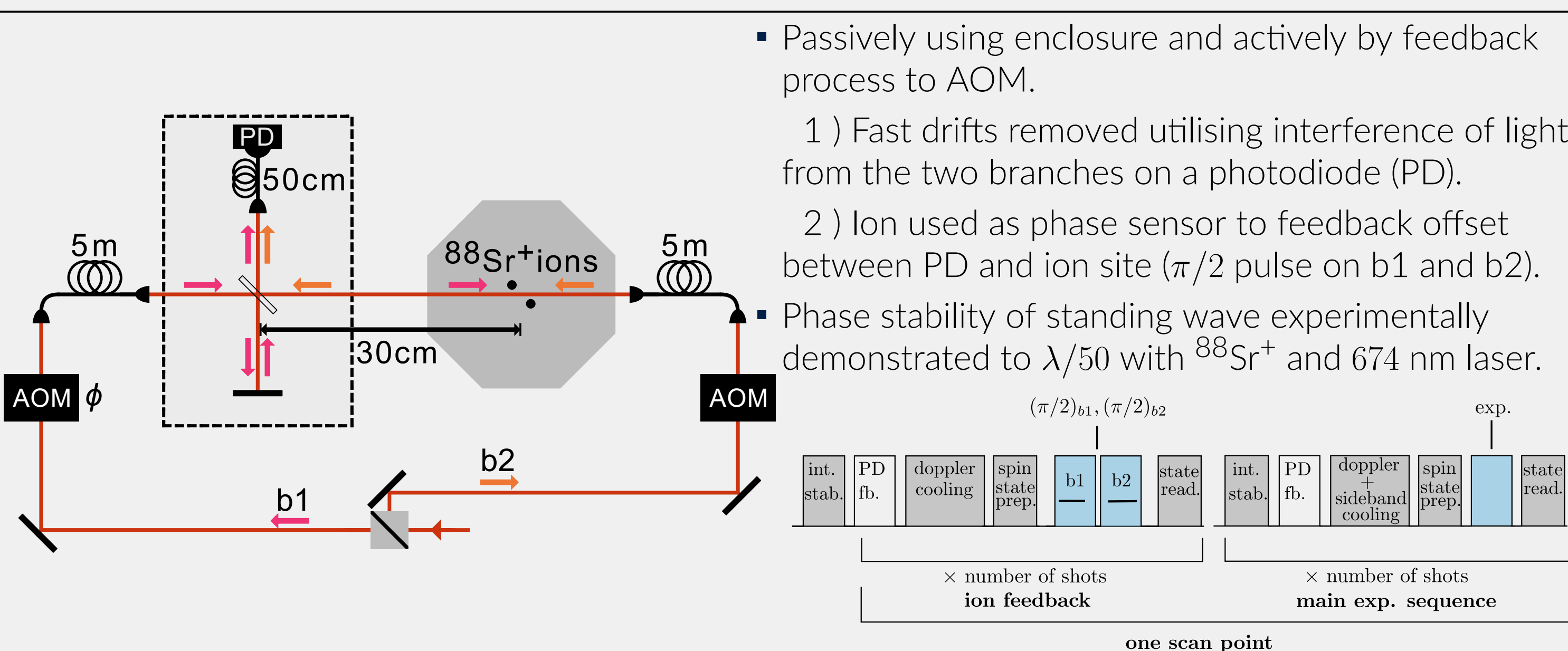
$$\hat{H}_{MS-SW} = \hbar 2\Omega\hat{S}_{\phi}\cos(\delta t)\sin(\Delta\phi/2) + \hbar 2\Omega\eta\hat{S}_{\phi}\cos(\delta t)(\hat{a}e^{-i\omega_z t} + \hat{a}^{\dagger}e^{i\omega_z t})\cos(\Delta\phi/2)$$

bichromatic standing wave



- Setting $\Delta\phi = 0$ (ions sitting at antinodes) we suppress the carrier term and maximise sideband coupling.
- This extra freedom allows fast gates by preventing the saturation effect seen in the travelling MS.
- However require keeping standing waves phase stable with respect to the ion position to perform coherent interactions.

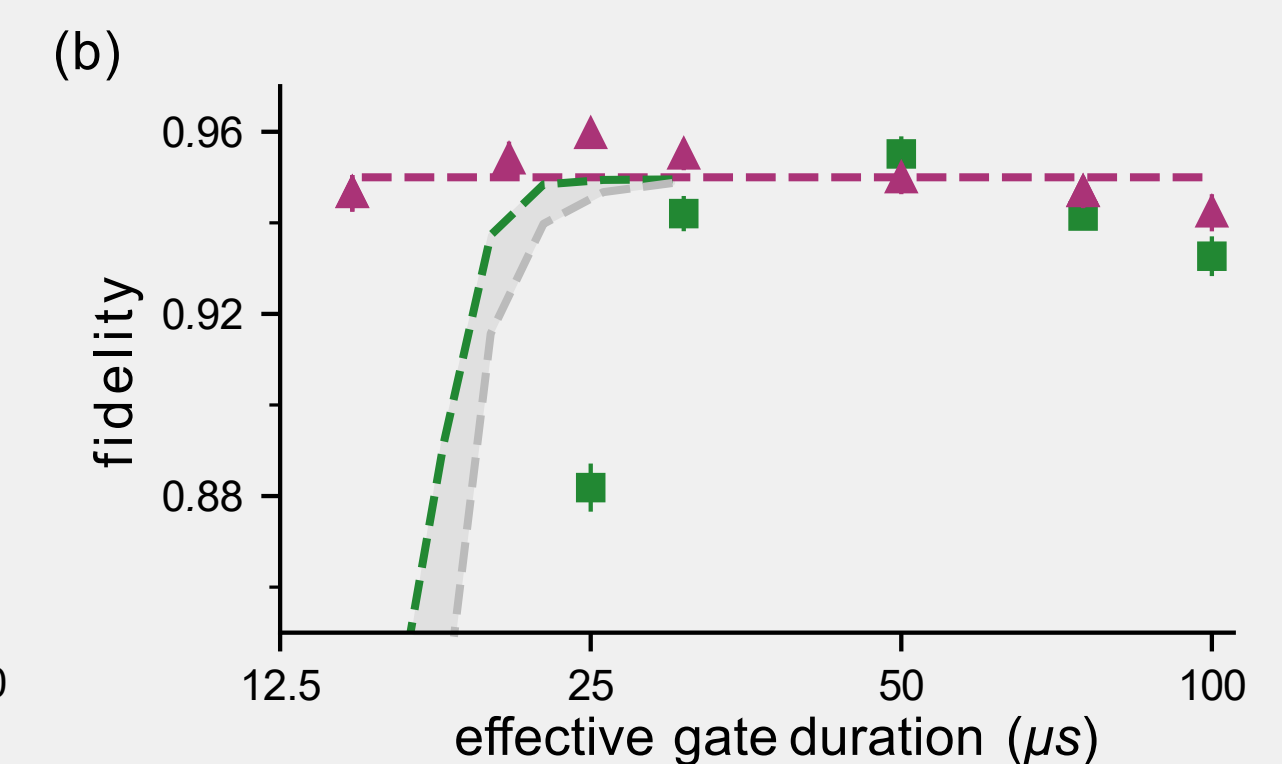
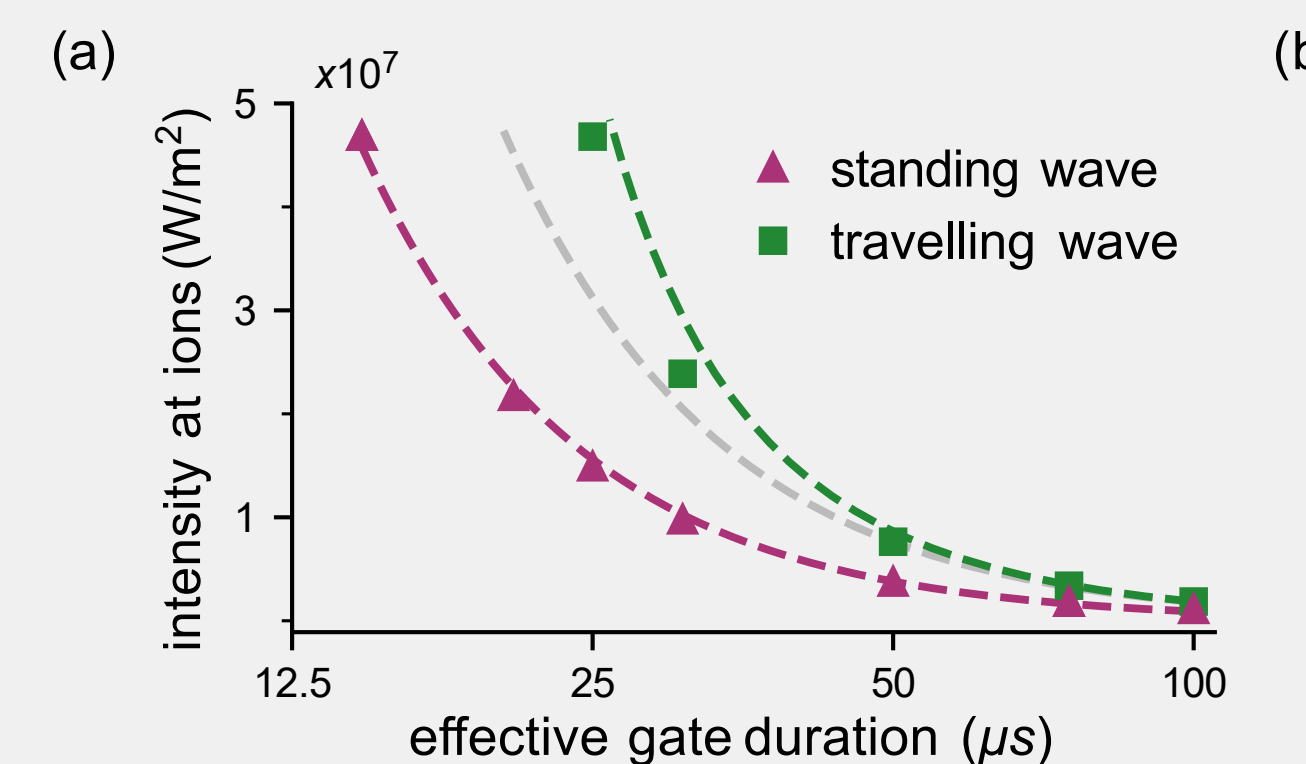
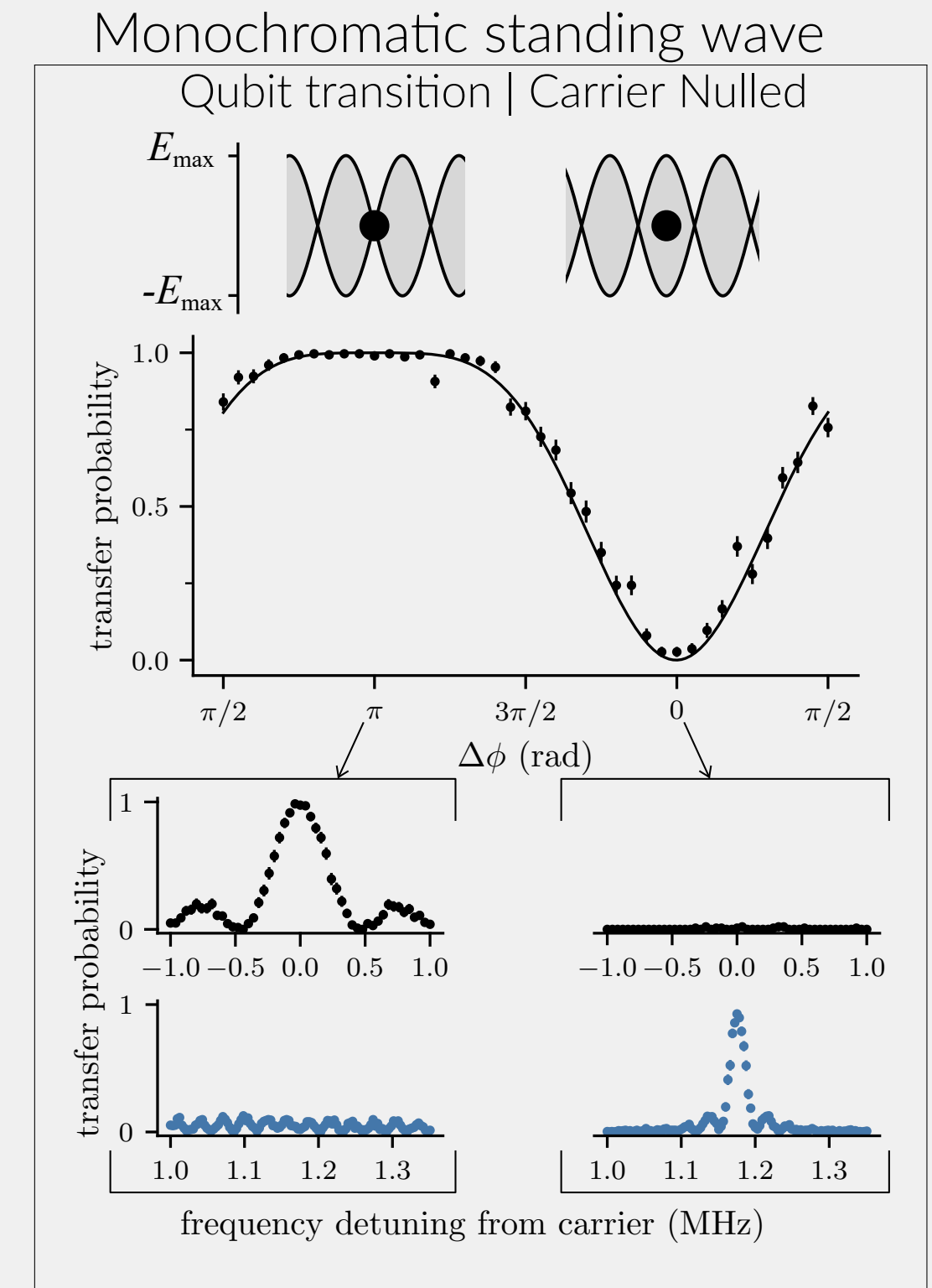
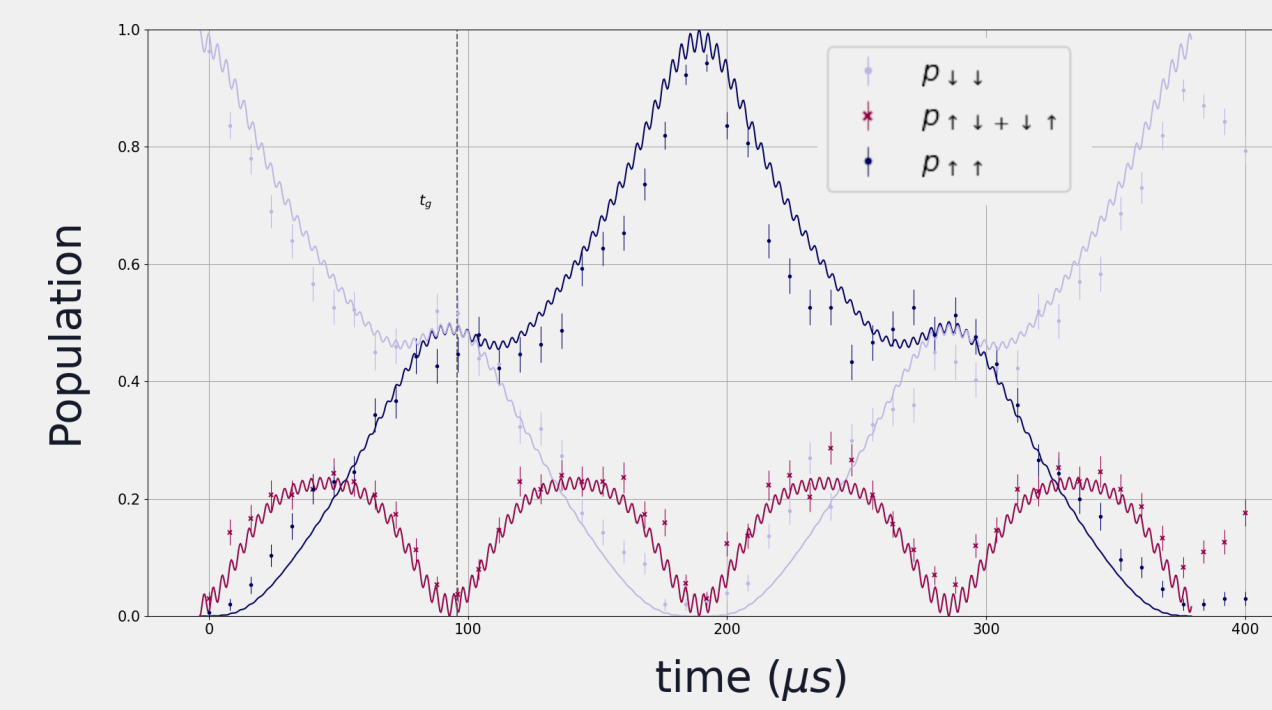
Phase Stabilization



- Passively using enclosure and actively by feedback process to AOM.
 - 1) Fast drifts removed utilising interference of light from the two branches on a photodiode (PD).
 - 2) Ion used as phase sensor to feedback offset between PD and ion site ($\pi/2$ pulse on b1 and b2).
- Phase stability of standing wave experimentally demonstrated to $\lambda/50$ with $^{88}\text{Sr}^+$ and 674 nm laser.

Carrier Nulling Results

- Experimental demonstration with $^{88}\text{Sr}^+$ and 674 nm laser.
- Standard Randomized Benchmarking of single qubit rotations found gate errors of $\epsilon = 0.173(3)\%$ for travelling wave, $\epsilon = 0.144(3)\%$ for standing wave.
- Universal gate set with phase stabilized standing-waves.
- Carrier suppression by 26 dB.
- Standing wave MS maintains $\geq 95\%$ fidelity at short gate durations in contrast to travelling wave MS sharp drop off at $\sim 25\mu\text{s}$.



New Platform

- New $^{40}\text{Ca}^+$ ion trap experiment in development for exploring fast gate regime using 729 nm quadrupole laser.
- Two high NA lenses create an array of singly addressing standing waves.
- 3D segmented trap design from NPL facilitates low heating rates (expected: < 10 q/s @ 1.5 MHz) whilst enabling ion shuttling and crystal rotations.
- MuMetal shield and permanent magnets for stable B field.

